TLP180

TOSHIBA Photocoupler IRED & Photo-Transistor

# **TLP180**

Telephone Use Equipment Programmable Controllers AC/DC-Input Module Telecommunication

The TOSHIBA mini flat coupler TLP180 is a small outline coupler, suitable for surface mount assembly.

TLP180 consist of a photo transistor, optically coupled to an infrared emitting diode connected inverse parallel, and can operate directly by AC input current.

- Collector-emitter voltage: 80 V (min)
- Current transfer ratio: 50% (min) Rank GB: 100% (min)
- Isolation voltage: 3750 Vrms (min)
- UL-recognized: UL 1577, File No.E67349
- cUL-recognized: CSA Component Acceptance Service No.5A File No.E67349
- VDE-approved: EN 60747-5-5 (Note 1)

Note 1: When a VDE approved type is needed, please designate the **Option(V4)**.

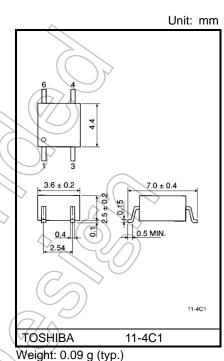
#### **Current Transfer Ratio**

Classi- fication		Ratio (%) (Ic/I <sub>F</sub> ) = 5 V, Ta = 25°C Max	Marking Of Classification
(Note 1) Standard	50	600	Blank, YE, GR, BL , GB
Rank Y	50	150	YE
Rank GR	100	300	GR
Rank BL	200	600	BL
Rank GB	100	600	GB , GR , BL

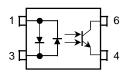
Note: The product with the Rank Y and BL are limited in production. For details, please contact your nearest Toshiba sales representative.

Note 1: Ex. rank GB: TLP180 (GB)

Note: Application type name for certification test, please use standard product type name, i.e. TLP180(GB): TLP180



## Pin Configuration (top view)



1: Anode, Cathode

- 3: Cathode, Anode
- 4: Emitter
- 6: Collector

Start of commercial production 1995-12

Absolute Maximum Ratings (Ta = 25°C)

	Characteristic	Symbol	Rating	Unit
	Forward current	I <sub>F(RMS)</sub>	±50	mA
	Forward current detating (Ta $\geq$ 53°C)	ΔI <sub>F</sub> /°C	-0.7	mA/°C
Ð	Pulse forward current (Note 1)	IFP	±1	A
	Diode power dissipation	PD	100	mW
	Diode power dissipation derating (Ta $\geq$ 53°C)	ΔP <sub>D</sub> /°C	-1.39	mW/°C
	Junction temperature	Тј	125	∘c
	Collector-emitter voltage	VCEO	80	5) v
	Emitter-collector voltage	V <sub>ECO</sub>	7	v
Detector	Collector current	IC	(50)	mA
Dete	Power dissipation	PC	150	mW
	Power dissipation derating (Ta ≥ 25°C)	ΔP <sub>C</sub> /°C	-1.5	mW/°C
	Junction temperature	Tj	125	<b>0°</b>
Storage temperature range		T <sub>stg</sub>	-55 to 125	00
Operating temperature range		Topr	-55 to 100	°C
Lead soldering temperature (10 s)		Tsol	260	<u> </u>
Total package power dissipation		RI	200	) mW
Tota	al package power dissipation derating (Ta $\ge$ 25°C)	ΔPT/°C	-2.0	mW/°C
Isola	ation voltage (AC, 60 s, R.H. $\leq$ 60 %) (Note 2)	BVs	3750	Vrms

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: Pulse width ≤ 100 µs, f = 100 Hz

Note 2: Device considered a two terminal device: Pins 1 and 3 shorted together and 4 and 6 shorted together.

#### **Recommended Operating Conditions**

Characteristic	Symbol	Min	Тур.	Max	Unit
Supply voltage	V <sub>CC</sub>	_	5	48	V
Forward current	IF(RMS)	—	16	20	mA
Collector current	lc	—	1	10	mA
Operating temperature	T <sub>opr</sub>	-25		85	°C

Note: Recommended operating conditions are given as a design guideline to obtain expected performance of the device. Additionally, each item is an independent guideline respectively. In developing designs using this product, please confirm specified characteristics shown in this document.

#### **Electrical Characteristics (Ta = 25°C)**

	Characteristic	Symbol	Test Condition	Min	Тур.	Max	Unit
Q	Forward voltage	VF	$I_F = \pm 10 \text{ mA}$	1.0	1.15	1.3	V
LED	Capacitance	CT	V = 0 V, f = 1 MHz	_	60	_	pF
	Collector-emitter breakdown voltage	V <sub>(BR)</sub> CEO	IC = 0.5 mA	80	_	_	V
2	Emitter-collector breakdown voltage	V <sub>(BR)ECO</sub>	I <sub>E</sub> = 0.1 mA	(7)	}_	_	V
Detecto	Collector dark current ICEO	V <sub>CE</sub> = 48 V (ambient light below 1000 k) (Note 1)	$\sim$	0.01 (2)	0.1 (10)	μA	
		ICEO	$V_{CE} = 48 \text{ V}, \text{ Ta} = 85^{\circ}\text{C}$ (ambient light below 1000 $\ell$ x) (Note 1)		2 (4)	50 (50)	μA
	Capacitance (collector to emitter)	CCE	V = 0 V, f = 1 MHz	_	10	_	pF

Note 1: Please use standard electric lamp to light up the device's marking surface.

### Coupled Electrical Characteristics (Ta = 25°C)

Symbol	Test Condition	Mìn	Тур.	Max	Unit
	$I_F = \pm 5 \text{ mA}, V_{CE} = 5 \text{ V}$	50	—	600	%
IC/IF	Rank GB	100	—	600	
	IF = ±1 mA, V <sub>CE</sub> = 0.4 V	) _	60	_	%
IC/IF(sat)	Rank GB	30	—		70
	$I_{C} = 2.4 \text{ mA}, I_{F} = \pm 8 \text{ mA}$	—	_	0.4	
VCE (sat)	$I_{C} = 0.2 \text{ mA}, I_{F} = \pm 1 \text{ mA}$	—	0.2	_	V
7	Rank GB	—	_	0.4	
IC(off)	V <sub>F</sub> = ± 0.7 V, V <sub>CE</sub> = 48 V	—	1	10	μA
IC(ratio)	IC (IF = -5 mA)/IC (IF = 5 mA) (Note 1)	0.33	1	3	_
	IC/IF IC/IF(sat) VCE (sat) IC(off)	IC/IF IC/IF IF = ±5 mA, VCE = 5 V Rank GB IC/IF(sat) IF = ±1 mA, VCE = 0.4 V Rank GB IC = 2.4 mA, IF = ±8 mA IC = 0.2 mA, IF = ±1 mA Rank GB IC(off) VF = ± 0.7 V, VCE = 48 V IC (IF = -5 mA)/IC (IF = 5 mA)	Ic/IF         IF = ±5 mA, VcE = 5 V         50           Ic/IF         IF = ±1 mA, VcE = 5 V         50           Ic/IF(sat)         IF = ±1 mA, VcE = 0.4 V         -           VcE (sat)         Ic = 2.4 mA, IF = ±8 mA         -           VcE (sat)         Ic = 0.2 mA, IF = ±1 mA         -           Ic = 0.2 mA, IF = ±1 mA         -           Ic(off)         VF = ± 0.7 V, VcE = 48 V         -           Ic (IF = -5 mA)/Ic (IF = 5 mA)         0.33	IC/IF       IF = ±5 mA, VCE = 5 V       50          IC/IF       IF = ±1 mA, VCE = 0.4 V        60         IC/IF(sat)       IF = ±1 mA, VCE = 0.4 V        60         IC/IF(sat)       IC = 2.4 mA, IF = ±8 mA           VCE (sat)       IC = 0.2 mA, IF = ±1 mA        0.2         Rank GB         1         IC = 0.7 V, VCE = 48 V        1         IC (off)       VF = ± 0.7 V, VCE = 48 V        1         IC (strip)       IC (IF = -5 mA)/IC (IF = 5 mA)       0.33       1	Ic/IF       IF = ±5 mA, VCE = 5 V       50       600         Ic/IF       IF = ±1 mA, VCE = 0.4 V       -       600         Ic/IF(sat)       IF = ±1 mA, VCE = 0.4 V       -       600         Ic/IF(sat)       IF = ±1 mA, VCE = 0.4 V       -       600         Ic/IF(sat)       IC = 2.4 mA, IF = ±8 mA       -       -         VCE (sat)       IC = 0.2 mA, IF = ±1 mA       -       0.2         Rank GB       -       0.4         Ic = 0.2 mA, IF = ±1 mA       -       0.2         Rank GB       -       10         Ic(off)       VF = ± 0.7 V, VCE = 48 V       -       1         Ic(IF = -5 mA)/Ic (IF = 5 mA)       0.33       1       3

Note 1: 
$$IC(ratio) = \frac{I_{C2}(I_F \neq I_{F2}, V_{CE} = 5V)}{I_{C1}(I_F = I_{F1}, V_{CE} = 5V)}$$

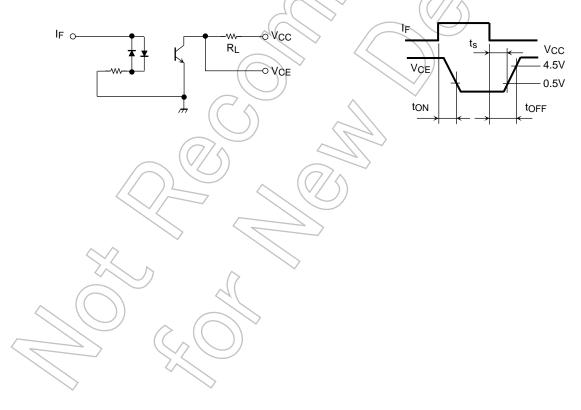
#### Isolation Characteristics (Ta = 25°C)

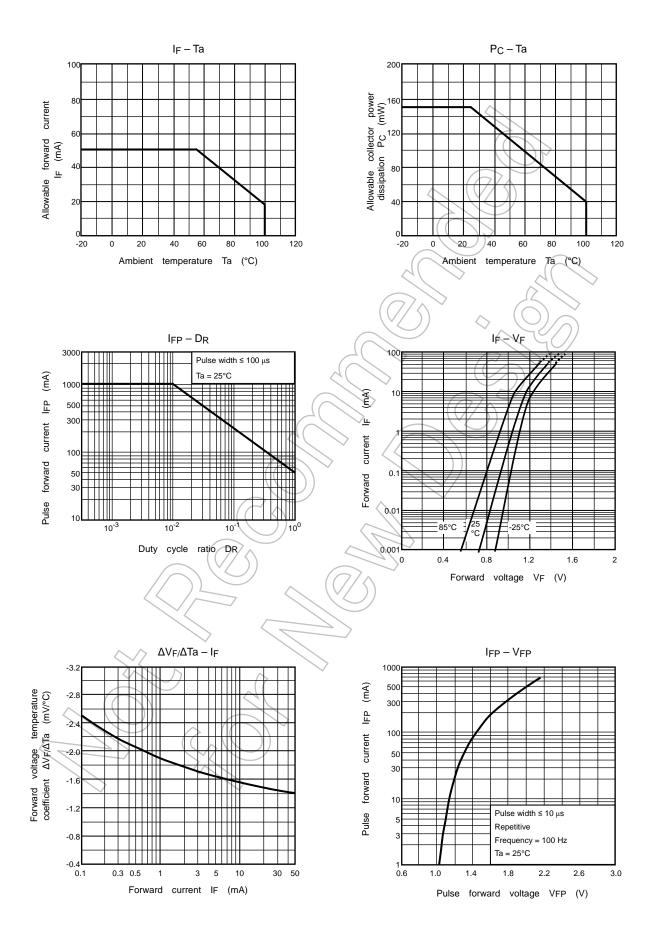
Characteristic	Symbol	Test Condition	Min	Тур.	Max	Unit
Capacitance input to output	CS	V <sub>S</sub> = 0 V, f = 1 MHz	_	0.8	_	pF
Isolation resistance	Rs	V <sub>S</sub> = 500 V, R.H. ≤ 60 %	5×10 <sup>10</sup>	10 <sup>14</sup>	_	Ω
Isolation voltage	BVS	AC, 60 s	3750		_	V <sub>rms</sub>

#### Switching Characteristics (Ta = 25°C)

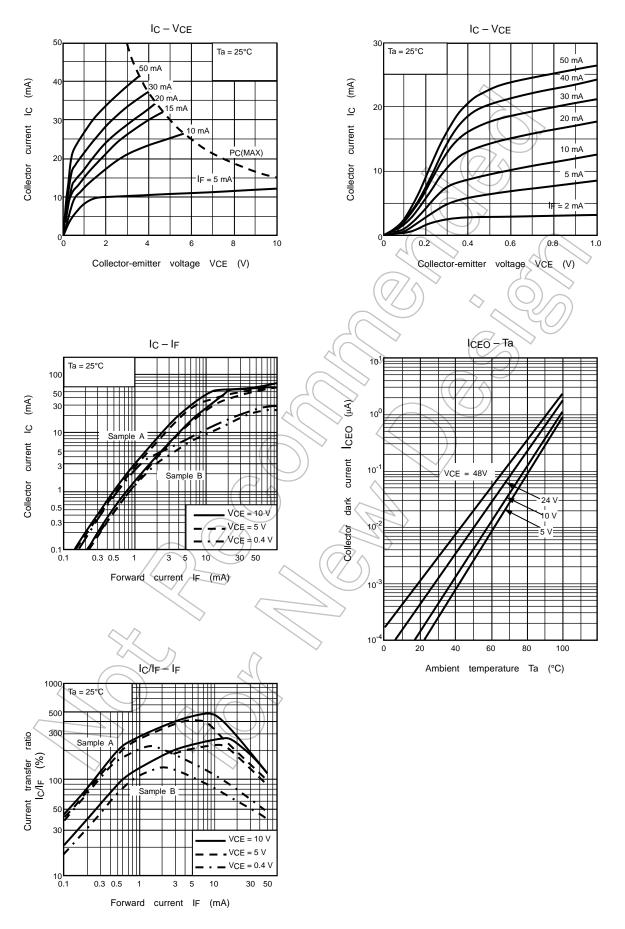
Characteristic	Symbol	Test Condition Min Typ. Max Unit
Rise time	tr	
Fall time	tf	$V_{CC} = 10 V, I_C = 2 mA$ $R_L = 100 Ω$ $\mu s$
Turn-on time	ton	$R_L = 100 \Omega$ $\mu$ s
Turn-off time	tOFF	
Turn-on time	ton	
Storage time	ts	$ \begin{array}{c c} R_L = 1.9 \ k\Omega & (Fig.1) \\ V_{CC} = 5 \ V, \ I_F = \pm 16 \ mA & 25 \ - \mu s \end{array} $
Turn-off time	tOFF	40 -

Fig. 1: Switching time test circuit

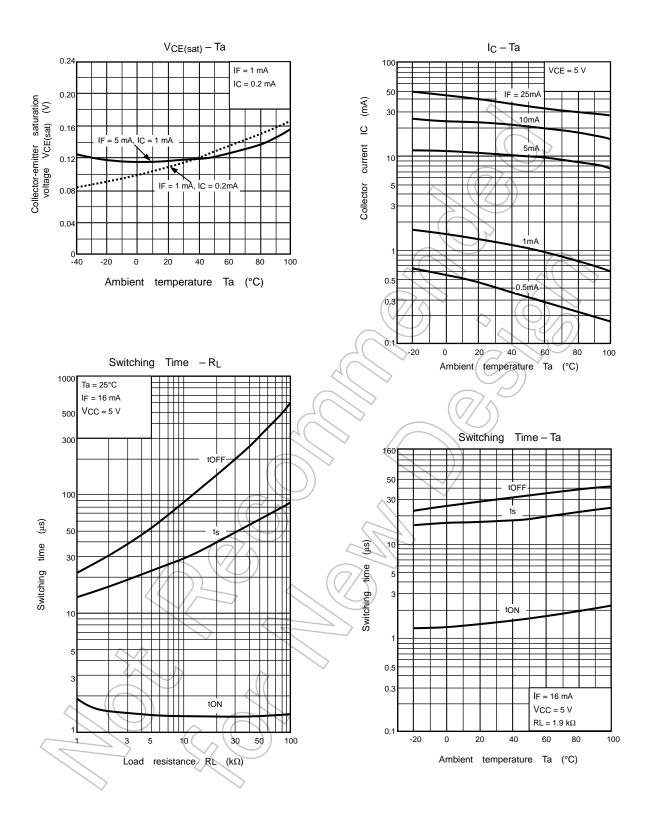




NOTE: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.



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